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Characteristic	Symbol	Value	Unit
Peak Pulse Power Dissipation (Note 5) 10/1000μs (Note 6) 8/20μs	P <sub>PK</sub>	225 1125	W
Peak Forward Surge Current, 8.3ms Single Half Sine Wave	I <sub>FSM</sub>	35	А

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
DC Steady-State Power Dissipation (Note 8)	P <sub>D</sub>	1.0	W
Thermal Resistance, Junction to Ambient (Note 8)	R <sub>0JA</sub>	330	°C/W
Thermal Resistance, Junction to Soldering Point (Note 9)	R <sub>θJS</sub>	70	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

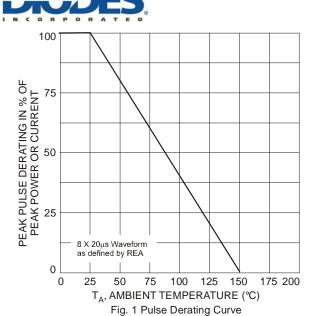
### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

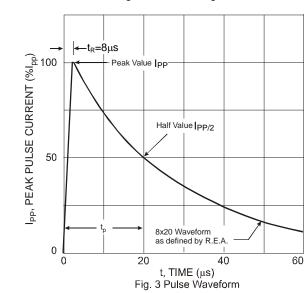
Part Number	Reverse Standoff Voltage	Breakdown Voltage V <sub>BR</sub> @ I <sub>T</sub> (Note 10)		Test Current	Max. Reverse Leakage @ V <sub>RWM</sub>	Max. Clamping Voltage @ I <sub>PP</sub>	Max. Peak Pulse Current (Note 5)	Marking Code
	V <sub>RWM</sub> (V)	Min (V)	Max (V)	I <sub>T</sub> (mA)	I <sub>R</sub> (μA)	V <sub>C</sub> (V)	IPP (A)	
DPD13AWF	13	14.4	15.9	1.0	1.0	21.5	10.5	TBG

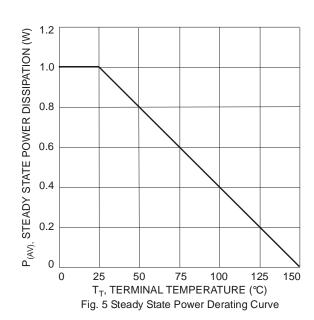
Notes:

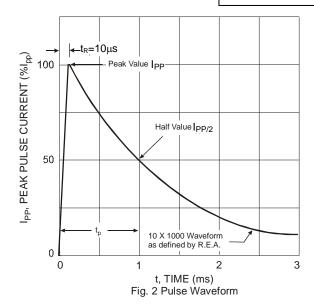
- 5. Non-Repetitive current pulse as shown in figure 2 and derated above  $T_A = +25$ °C as per figure 2.
- 6. Non-Repetitive current pulse as shown in figure 3 and derated above  $T_A = +25$ °C as per figure 3.
- 7. 1/2 sine wave (or eTuivalent sTuare wave), pulse width = 8.3ms, duty cycle = 4 pulses/minute maximum.

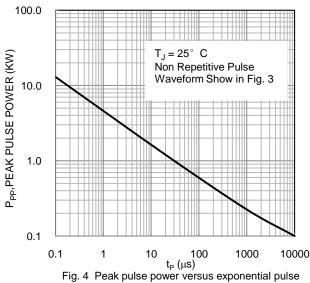
  8. Device mounted on 1"x1", FR-4 PCB; 2 oz. Cu pad layout. Cathode pad dimensions 5.5mm x 3.5mm. Anode pad dimensions 2.25mm x 3.5mm.
- 9. Theoretical  $R_{0JS}$  calculated from the top center of the die straight down to the PCB/cathode tab solder junction.
- 10.  $V_{BR}$  measured at pulse test current  $I_T$  with tp  $\leq$ 5.0ms at  $T_A$  = +25°C.



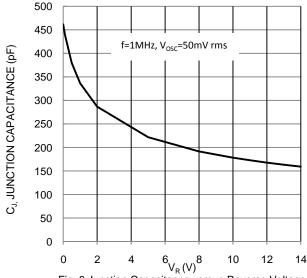








duration

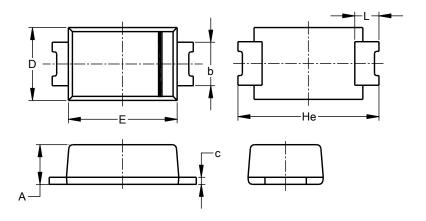




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOD123F (Type B)

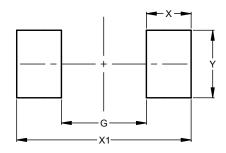


S	SOD123F (Type B)				
Dim	Min	Max	Тур		
Α	0.81	1.15	_		
b	0.80	1.35	_		
С	0.05	0.30			
D	1.70	1.90	1.80		
Е	2.60	2.80	2.70		
He	3.30	3.70	3.50		
L	0.35	0.85	_		
All	All Dimensions in mm				

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOD123F (Type B)



Dimensions	Value (in mm)	
G	1.90	
Х	1.00	
X1	3.90	
	1.50	



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